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FAIRCHILD

SEMICONDUCTOR TM

FQA9P25 250V P-Channel MOSFET

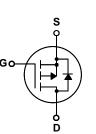
General Description

These P-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advanced technology is especially tailored to minimize on-state resistance, provide superior switching performance, and withstand a high energy pulse in the avalanche and commutation modes. These devices are well suited for high efficiency switching DC/DC converters.

Features

- -10.5A, -250V, $R_{DS(on)}$ = 0.62 Ω @V_{GS} = -10 V Low gate charge (typical 29 nC)
- Low Crss (typical 27 pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- TO-3PN GDS FQA Series



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter		FQA9P25	Units	
V _{DSS}	Drain-Source Voltage		-250	V	
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$) - Continuous ($T_C = 100^{\circ}C$)		-10.5	А	
			-6.6	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	-42	А	
V _{GSS}	Gate-Source Voltage		± 30	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	650	mJ	
I _{AR}	Avalanche Current	(Note 1)	-10.5	А	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	15	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	-5.5	V/ns	
PD	Power Dissipation (T _C = 25°C)		150	W	
	- Derate above 25°C		1.2	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C	

Thermal Characteristics

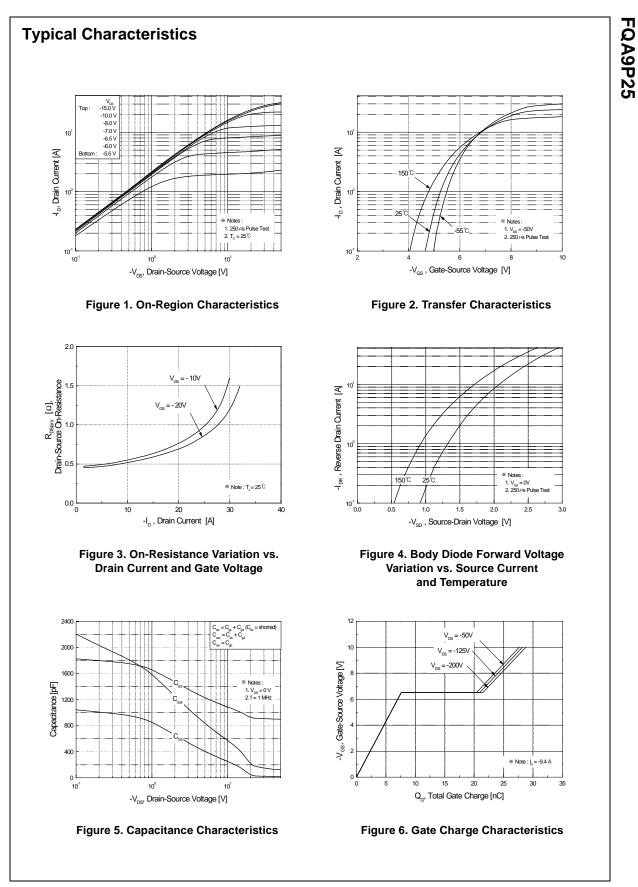
Symbol	Parameter	Тур	Max	Units
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case		0.83	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink	0.24		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		40	°C/W

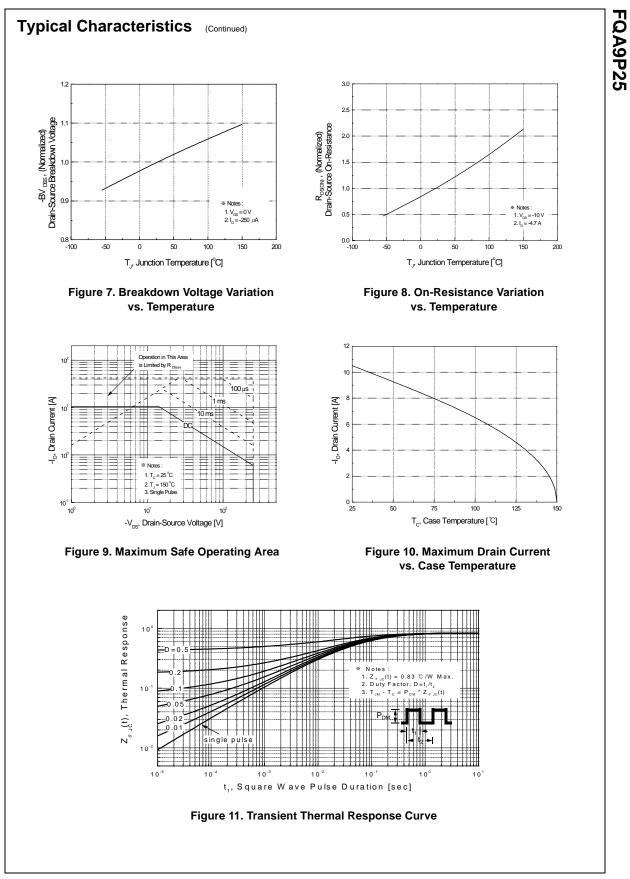
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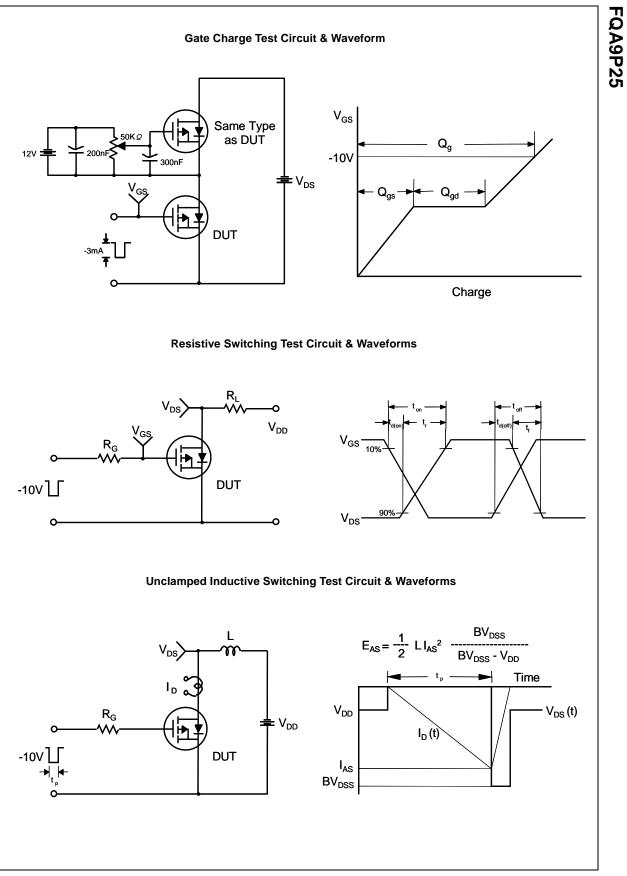
ТМ

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = -250 μA	-250			V
ΔBV _{DSS} / ΔT _{.1}	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-0.2		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -250 V, V _{GS} = 0 V			-1	μA
		V _{DS} = -200 V, T _C = 125°C			-10	μA
I _{GSSF}	Gate-Body Leakage Current, Forward	$V_{GS} = -30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			100	nA
On Ch					1	1
V _{GS(th)}	aracteristics Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = -250 μA	-3.0		-5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -5.25 \text{ A}$		0.48	0.62	Ω
9fs	Forward Transconductance	V _{DS} = -40 V, I _D = -5.25 A (Note 4)		6.1		S
C _{iss}	ic Characteristics Input Capacitance	V _{DS} = -25 V, V _{GS} = 0 V,		910	1180	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		170	220	pF
C _{rss}	Reverse Transfer Capacitance			27	35	pF
Switch	ing Characteristics	V 405 V 1 0 4 4		20	50	ns
t _r	Turn-On Rise Time	$V_{DD} = -125 \text{ V}, \text{ I}_{D} = -9.4 \text{ A},$		150	310	ns
t _{d(off)}	Turn-Off Delay Time	$R_G = 25 \Omega$		45	100	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		65	140	ns
Qg	Total Gate Charge	V _{DS} = -200 V, I _D = -9.4 A,		29	38	nC
-	Gate-Source Charge	$V_{GS} = -10 V$		7.6		nC
Q _{as}	Gate-Drain Charge	(Note 4, 5)		14		nC
Q _{gs} Q _{gd}	Cate Brain Charge	(1	
Q _{gd} Drain-S	ource Diode Characteristics a	nd Maximum Ratings	1		1	1
Q _{gd} Drain-S	Source Diode Characteristics an Maximum Continuous Drain-Source Dio	nd Maximum Ratings			-10.5	A
Q _{gd} Drain-\$ I _S I _{SM}	Source Diode Characteristics an Maximum Continuous Drain-Source Dio Maximum Pulsed Drain-Source Diode F	nd Maximum Ratings ode Forward Current Forward Current			-42	A A
Q _{gd} Drain-S	Source Diode Characteristics an Maximum Continuous Drain-Source Dio	nd Maximum Ratings ode Forward Current Forward Current V _{GS} = 0 V, I _S = -10.5 A				
Q _{gd} Drain-\$ I _S I _{SM}	Source Diode Characteristics an Maximum Continuous Drain-Source Dio Maximum Pulsed Drain-Source Diode F	nd Maximum Ratings ode Forward Current Forward Current			-42	A

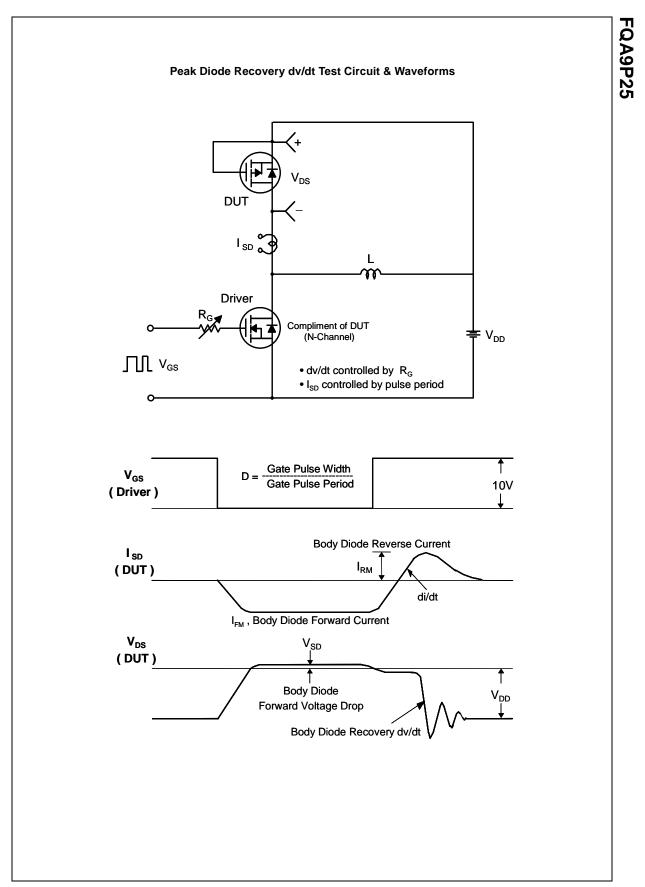


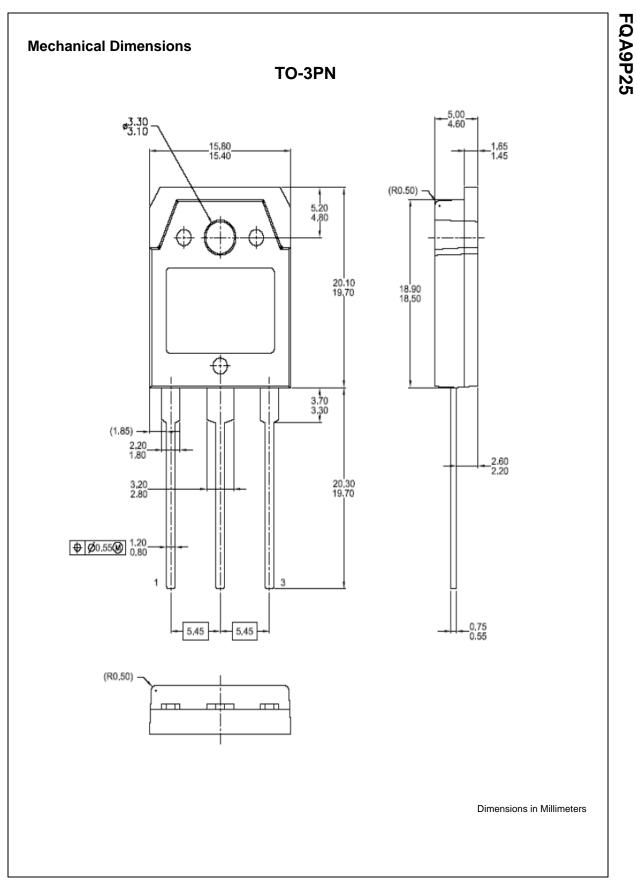


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